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Advanced School on Synchrotron and Free Electron Laser Sources and their Multidisciplinary Applications

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IR spectroscopy and microscopy in material science

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IR spectroscopy and microscopy in material science

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Outline - Selected applications of IRSR in solid state physics

• Superconductivity

- 1. Optical properties of superconductors
- 2. The two gaps of superconducting MgB_2
- 3. Pump-probe experiments in the far-infrared on Pb film

• High-pressure measurements

- 1. Tuning the Peierls instability on RE dichalchogenides
- 2. Inducing Metal to Insulator Transition: the example of VO_2
- Imaging in solid state physics
 - 1. Electric field induced phase transition in VO_2 films
 - 2. IR Imaging of phase separation

Advantages of IRSR



Small samples
Extreme experimental conditions (high pressure, high magnetic field)
Spatial resolution (microscopy)

Flux gain in the THz range \rightarrow \rightarrow \rightarrow

≈ 10 with incoherent IRSR
> 10⁴ with coherent IRSR (CSR) see next talk



Superconductivity

Superconductivity today

1. Looking for new materials

- 1986: High-T_c cuprates
- 1990: C₆₀ fullerene
- 2000: MgB₂
- 2003: Na_xCoO₂·3H₂O
- 2004: B-doped diamond

2. Understanding new materials

Superconductivity is ruled by low-energy electrodynamics:

- Superconducting gap : THz-range
- Spectral weight of condensate and penetration depth:THz-range
 - Mediators of pairing (phonons, etc.): Far-infrared
 - Range of sum rules: Far-, Mid-, or Near-infrared
 - Free-carrier conductivity above T_c: Infrared

Magnetic levitation





MALEV in Shanghai (liquid-He cooled) Lifting a Sumo wrestler (LN₂ cooling)

Basic optics of superconductors

Minimum excitation energy: Cooper-pair breaking 2Δ

Superconducting gap observed if: •sample in the dirty-limit $(2\Delta < \Gamma)$ •Cooper pairs in s-wave symmetry



Ferrel-Glover-Tinkham Rule

Reflectivity set-up

Interferometer



Reference: gold evaporated *in situ* Reflectivity: $R = I_R^{crys}/I_R^{gold}$ \downarrow Kramers-Kronig transf. \downarrow optical conductivity $\sigma(\omega)$

Single crystals may be very small:



The 39 K superconductor MgB₂



Multiband superconductivity in MgB₂



Reflectivity of MgB₂ measured with a conventional source (Hg-lamp)



A. Perucchi et al., PRL 89, 097001 (2002)

A synchrotron study of MgB₂ on ultra-clean films



The π -gap feature is enhanced by impurities To observe the σ -gap a very high signal to noise ratio is needed! ($\Delta R < 0.5\%$ @ THz frequencies) **Pump-probe experiments**



Temporal resolution is determined by:

- Synchrotron beam pulse-width Δt
- Pump pulse-width (fs laser)
- Jitter

 Δt is typically 10's of ps, but can be reduced to below 1 ps under special conditions as low- α (cfr. next talk) or femtoslicing **Pump-probe experiments**



G. L. Carr et al., PRL 85, 3001 (2000)

- 1. Pump photons $(hv>2\Delta_o)$ break Cooper pairs thus creating high energy $(>> E_F)$ QP's
- 2. Very quickly (<ps) QP's relax to lower energies and accumulate at the gap edge (b)
- 3. Recombination into Cooper pairs dominated by the phonon bottleneck effect (c)

From Rothwarf-Taylor equations

$$\tau_{eff} = \tau_{\gamma} (1 + \frac{\tau_R}{2\tau_B})$$

Pump-probe experiments on Pb film





Long relaxation (20 ns): extrinsic effect (heating)
Short relaxation (250 ps): consistent with Rothwarf and Taylor model

Time resolved frequency-dependent data demonstrate a gap reduction of 0.6% at 0.4 nJ pump pulse energy (empty circles) and 3% for 1.8 nJ (full circles)

G. L. Carr et al., PRL 85, 3001 (2000)

High Pressures

Diamond Anvil Cell (DAC)









 $R_{dia/sam} = I_R / I_0$

Infrared measurements at high pressure

Infrared spectroscopy is a bulk, contactless technique which probes both electronic and phononic excitations over a broad energy range



With $n_d=2.43$ being the diamond refractive index

The full determination of the optical constants can be achieved through:

- Simultaneous measurement of R and T
- Lorentz-Drude fitting
- Kramers-Kronig Transformations



Hydrostatic pressure vs. chemical pressure



With increasing P, $R(\omega)$ increases between 2000 and 5000 cm⁻¹

The same kind of behavior is observed by applying chemical pressure (substitution of the Rare Earth ion).

A. Sacchetti et al., PRL 98, 026401 (2007)

Optical conductivity



A. Sacchetti et al., PRL 98, 026401 (2007)

The optical conductivity is recovered through a fitting of the reflectivity data.

It is then possible to give an estimate for the single particle-gap energy.

Single-particle gap



A. Sacchetti et al., PRL 98, 026401 (2007)





The band theory is properly defined in the one-electron approximation, i.e. when W is much larger than other electronic energy scales

$$W >> U, e - ph$$

Mott-Hubbard insulators



metal Mott Insulator metal Filling-controlled MIT Bandwidth-controlled MIT I

U prevents double on-site occupancy the opening of a gap in the spectra of excitations is induced

$$H = -t \sum_{\langle i,j \rangle,\sigma} c_{i,\sigma}^{\dagger} c_{j,\sigma} + U \sum_{i=1}^{N} n_{i\uparrow} n_{i\downarrow}$$

Electron-electron interaction and insulator to metal transition (MIT)



Electronic correlation: failure of band model

Pressure may increase the W/U ratio inducing a MIT

W: bandwidth or kinetic energy (strongly dependent on atomic distances) **U** : coulomb repulsion

The metal-insulator transition in VO₂

T<340 K

Insulating monoclinic (M1) phase Dimerization and tilting of V pairs MIR Optical gap

T>340 K

Metallic rutile (R) phase With a resistivity jump of several order of magnitude



Rutile structure (picture taken from V. Eyert)

P-dependent reflectance and transmittance of VO₂



 $R(\omega)$ increases above 10 GPa

 $T(\omega)$ continuously decreases

Optical conductivity of VO₂ under high pressure



For P<P* the optical gap decreases in energy

For P>P* the gap seems to be completely closed $\sigma_1(\omega) \rightarrow 0$ for $\omega \rightarrow 0$

Raman spectroscopy on VO₂ under high pressure



Phonon frequency hardening above P*=10 GPa without significant changes in the peak pattern

Two regimes:

P<P*: weak P-dependence P>P*: rearrangements of V chains within a monoclinic framework

New high-P monoclinic phase ?

E. Arcangeletti et al., PRL 98 196406 (2007)

Imaging

Electric field induced phase transition in VO₂



Study of the temporally and spatially resolved optical response.

Temporal resolution on the μs time-scale is achieved through the fast response of the MCT (HgCdTe) detector.

No role for Synchrotron in this case: the pulsed structure of synchrotron is useful to reach *ns* and below.

Spatial resolution (5 μ m) is obtained by coupling IR synchrotron radiation with a microscope.

Role for Synchrotron Brightness Gain

J.-S. Lee et al., Appl. Phys. Lett. 91, 133509 (2007)

Electric field induced phase transition in VO₂



The spatially resolved optical response permits to explain the differences in voltage switching in terms of sample inhomogeneities which favor the creation of conducting paths (possible role of oxygen deficiencies).

J.-S. Lee et al., Appl. Phys. Lett. 91, 133509 (2007)

Microscopy in solid state physics

The frequency of the υ_3 (a_g) phonon mode gives indication on the metallic nature of κ -(BEDT-TTF)₂X.

This enables imaging of phase separation on the micrometer scale.

T. Sasaki *et al*. PRL **92**, 227001

Imaging of phase separation in κ-(BEDT-TTF)₂X



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and many others.....